NSN 5961-00-835-6448 Transistor - Page 1 of 2



View Online at https://aerobasegroup.com/nsn/5961-00-835-6448
Inclosure Material:
Metal
Overall Length:
Between 0.240 inches and 0.260 inches
Terminal Length:
1.500 inches
Overall Diameter:
Between 0.335 inches and 0.370 inches
Internal Configuration:
Unijunction
Mounting Method:
Terminal
Terminal Circle Diameter:
0.200 inches
Features Provided:
Hermetically sealed case
Semiconductor Material:
Silicon
Voltage Rating In Volts Per Characteristic:
60.0 emitter to base voltage, dc
Current Rating Per Characteristic:
70.00 milliamperes repetitive peak forward current megahertz and 2.00 microamperes repetitive peak forward current nanoamperes
Power Rating Per Characteristic:
600.0 milliwatts small-signal input power, common-collector preset
Maximum Operating Tempurature Per Measurement Point:
175.0 degrees celsius junction
Special Features:
Junction pattern arrangement: pn
Precious Material And Location:
Terminal surfaces gold
Precious Material:
Gold
Test Data Document:
81349-mil-s-19500 specification (includes engineering type bulletins, brochures, etc., that reflect specification type data in specification
format; excludes commercial catalogs, industry directories, and similar trade publications, reflecting general type data on certain
environmental and performance requirements and test conditions that are shown as "typical", "average", "", etc.).
Terminal Type And Quantity:
3 uninsulated wire lead
Specification Data:
81349-mil-s-19500/75 government specification
Shelf Life:
N/a

Unit Of Measure:

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No

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